

TXB0102 2-Bit Bidirectional Voltage-Level Translator With Auto Direction Sensing and ± 15 -kV ESD Protection

1 Features

- Available in the Texas Instruments NanoFree™ Packages
- 1.2 V to 3.6 V on A Port and 1.65 V to 5.5 V On B Port ($V_{CCA} \leq V_{CCB}$)
- V_{CC} Isolation Feature – If Either V_{CC} Input Is at GND, All Outputs Are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption, 4- μ A Max I_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - A Port
 - 2500-V Human-Body Model (A114-B)
 - 200-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)
 - B Port
 - 15-kV Human-Body Model (A114-B)
 - 200-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)

2 Applications

- Handsets
- Smartphones
- Tablets
- Desktop PCs

3 Description

This 2-bit noninverting translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes. V_{CCA} should not exceed V_{CCB} .

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

NanoFree™ technology is a major breakthrough in IC packaging concepts, using the die as the package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TXB0102	SSOP (8)	2.95 mm × 2.80 mm
	VSSOP (8)	2.30 mm × 2.00 mm
	DSBGA (8)	0.90 mm × 1.80 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Typical Operating Circuit

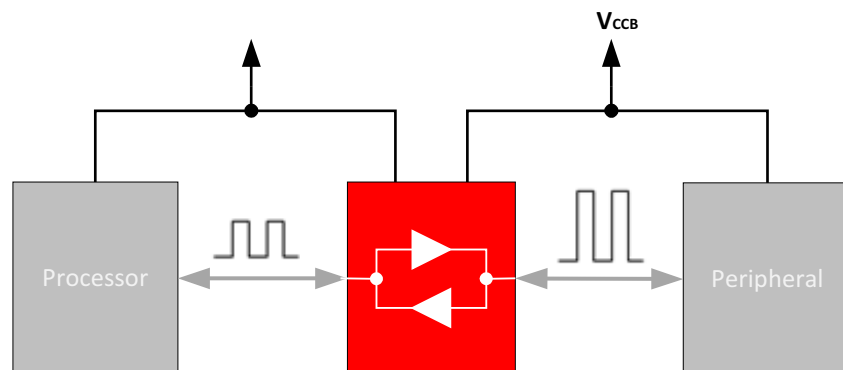


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (March 2012) to Revision C Page

Added <i>Pin Configuration and Functions</i> section, <i>Handling Rating</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1
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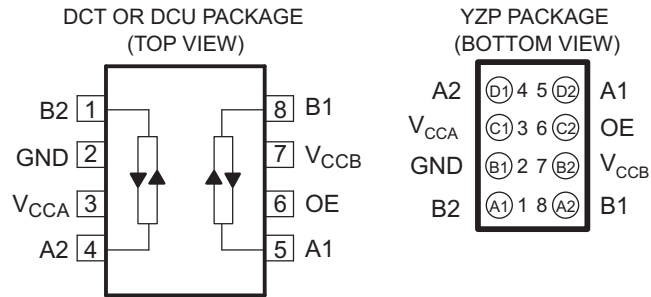
Changes from Revision A (January 2011) to Revision B Page

Added notes to pin out graphics	3
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Changes from Original (May 2007) to Revision A Page

Added ball labels to the YZP Package	3
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5 Pin Configuration and Functions



- Pullup resistors are not required on both sides for Logic I/O.
- If pullup or pulldown resistors are needed, the resistor value must be over 50 k Ω .
- 50 k Ω is a safe recommended value, if the customer can accept higher V_{OL} or lower V_{CCOUT} , smaller pullup or pulldown resistor is allowed, the draft estimation is $V_{OL} = V_{CCOUT} \times 4.5k / (4.5k + R_{pu})$ and $V_{OH} = V_{CCOUT} \times R_{dw} / (4.5k + R_{dw})$.
- If pullup resistors are needed, please refer to the TXS0102 or contact TI.
- For detailed information, please refer to application note [SCEA043](#).

Pin Functions: YZP

PIN			TYPE ⁽¹⁾	DESCRIPTION
BALL	NO.	NAME		
A1	1	B2	I/O	Input/output B. Referenced to V_{CCB} .
A2	5	B1	I/O	Input/output A1. Referenced to V_{CCA} .
B1	2	GND	S	Ground
B2	6	V_{CCB}	I	3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
C1	3	V_{CCA}	S	A-port supply voltage. $1.1\text{ V} \leq V_{CCA} \leq 3.6\text{ V}$, $V_{CCA} \leq V_{CCB}$
C2	7	OE	S	B-port supply voltage. $1.65\text{ V} \leq V_{CCB} \leq 5.5\text{ V}$
D1	4	A2	I/O	Input/output A2. Referenced to V_{CCA} .
D2	8	A1	I/O	Input/output B1. Referenced to V_{CCB} .

(1) (1) I = input, O = output, I/O = input and output, S = power supply

Pin Functions: DCT or DCU

PIN		TYPE ⁽¹⁾	DESCRIPTION
NO.	NAME		
1	B2	I/O	Input/output B. Referenced to V_{CCB} .
2	GND	S	Ground
3	V_{CCA}	S	A-port supply voltage. $1.1\text{ V} \leq V_{CCA} \leq 3.6\text{ V}$, $V_{CCA} \leq V_{CCB}$
4	A2	I/O	Input/output A2. Referenced to V_{CCA} .
5	A1	I/O	Input/output A1. Referenced to V_{CCA} .
6	OE	I	3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
7	V_{CCB}	S	B-port supply voltage. $1.65\text{ V} \leq V_{CCB} \leq 5.5\text{ V}$
8	B1	I/O	Input/output B1. Referenced to V_{CCB} .

(1) (1) I = input, O = output, I/O = input and output, S = power supply

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	Supply voltage range		–0.5	4.6	V
V _{CCB}	Supply voltage range		–0.5	6.5	
V _I	Input voltage range ⁽²⁾	A port	–0.5	4.6	V
		B port	–0.5	6.5	
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	A port	–0.5	4.6	V
		B port	–0.5	6.5	
V _O	Voltage range applied to any output in the high or low state ^{(2) (3)}	A port	–0.5	V _{CCA} + 0.5	V
		B port	–0.5	V _{CCB} + 0.5	
I _{IK}	Input clamp current	V _I < 0		–50	mA
I _{OK}	Output clamp current	V _O < 0		–50	mA
I _O	Continuous output current			±50	mA
Continuous current through V _{CCA} , V _{CCB} , or GND				±100	mA

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

6.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature range		–65	150	°C
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ , A Port		2500	V
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ , B Port	–15	15	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾ , A Port		1500	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾ , B Port		1500	
		Machine model (MM,A115-A), A Port		200	
		Machine model (MM,A115-A), B Port		200	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions^{(1) (2)}

			V _{CCA}	V _{CCB}	MIN	MAX	UNIT
V _{CCA}	Supply voltage				1.2	3.6	V
V _{CCB}					1.65	5.5	
V _{IH}	High-level input voltage	Data inputs	1.2 V to 3.6 V	1.65 V to 5.5 V	V _{CCI} × 0.65 ⁽³⁾	V _{CCI}	V
		OE input	1.2 V to 3.6 V	1.65 V to 5.5 V	V _{CCA} × 0.65	5.5	
V _{IL}	Low-level input voltage	Data inputs	1.2 V to 5.5 V	1.65 V to 5.5 V	0	V _{CCI} × 0.35 ⁽³⁾	V
		OE input	1.2 V to 3.6 V	1.65 V to 5.5 V	0	V _{CCA} × 0.35	
V _O	Voltage range applied to any output in the high-impedance or power-off state	A port	1.2 V to 3.6 V	1.65 V to 5.5 V	0	3.6	V
		B port			0	5.5	

- (1) The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.
- (2) V_{CCA} must be less than or equal to V_{CCB} and must not exceed 3.6 V.
- (3) V_{CCI} is the supply voltage associated with the input port.

Recommended Operating Conditions⁽¹⁾ (2) (continued)

		V_{CCA}	V_{CCB}	MIN	MAX	UNIT
$\Delta t/\Delta v$	Input transition rise or fall rate	A port inputs	1.2 V to 3.6 V	1.65 V to 5.5 V	40	ns/V
		B port inputs	1.2 V to 3.6 V	1.65 V to 1.95 V	40	
				4.5 V to 5.5 V	30	
T_A	Operating free-air temperature			–40	85	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TXB0102			UNIT
		DCT	DCU	YZP	
		8 PINS			
R _{θJA}	Junction-to-ambient thermal resistance	168.7	199.1	105.8	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	111.7	72.4	1.6	
R _{θJB}	Junction-to-board thermal resistance	78.1	77.8	10.8	
ψ _{JT}	Junction-to-top characterization parameter	45.0	6.2	3.1	
ψ _{JB}	Junction-to-board characterization parameter	77.5	77.4	10.9	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics⁽¹⁾ (2)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A = 25°C			−40°C to 85°C		UNIT
					MIN	TYP	MAX	MIN	MAX	
V _{OHA}		I _{OH} = −20 μA	1.2 V		1.1			V _{CCA} − 0.4		V
			1.4 V to 3.6 V							
V _{OLA}		I _{OL} = 20 μA	1.2 V		0.3			0.4		V
			1.4 V to 3.6 V							
V _{OHB}		I _{OH} = −20 μA		1.65 V to 5.5 V				V _{CCB} − 0.4		V
V _{OLB}		I _{OL} = 20 μA		1.65 V to 5.5 V				0.4		V
I _I	OE	V _I = V _{CCI} or GND	1.2 V to 3.6 V	1.65 V to 5.5 V				±1	±2	μA
I _{off}	A port	V _I or V _O = 0 to 3.6 V	0 V	0 V to 5.5 V				±1	±2	μA
	B port	V _I or V _O = 0 to 5.5 V	0 V to 3.6 V	0 V				±1	±2	
I _{OZ}	A or B port	OE = GND	1.2 V to 3.6 V	1.65 V to 5.5 V				±1	±2	μA
I _{CCA}		V _I = V _{CCI} or GND, I _O = 0	1.2 V	1.65 V to 5.5 V	0.06					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				3		
			3.6 V	0 V				2		
			0 V	5.5 V				−2		
I _{CCB}		V _I = V _{CCI} or GND, I _O = 0	1.2 V	1.65 V to 5.5 V	3.4					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
			3.6 V	0 V				−2		
			0 V	5.5 V				2		
I _{CCA} + I _{CCB}		V _I = V _{CCI} or GND, I _O = 0	1.2 V	1.65 V to 5.5 V	3.5					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				8		
I _{CCZA}		V _I = V _{CCI} or GND, I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V	0.05					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				3		

(1) V_{CCI} is the supply voltage associated with the input port.

(2) V_{CCO} is the supply voltage associated with the output port.

Electrical Characteristics^{(1) (2)} (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A = 25°C			–40°C to 85°C		UNIT
					MIN	TYP	MAX	MIN	MAX	
I _{CCZB}		V _I = V _{CCI} or GND, I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V	3.3					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
C _i	OE		1.2 V to 3.6 V	1.65 V to 5.5 V	2.5			3		pF
C _{io}	A port		1.2 V to 3.6 V	1.65 V to 5.5 V	5			6		pF
	B port				11			14		

6.6 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V _{CCA}							UNIT
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V	
			V _{CCB}							
			5 V	1.8 V	1.8 V	1.8 V	2.5 V	5 V	3.3 V to 5 V	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP	
C _{pdA}	A port input, B port output	C _L = 0, f = 10 MHz, t _r = t _f = 1 ns, OE = V _{CCA} (outputs enabled)	7.8	8	8	7	7	8	8	pF
	B port input, A port output		12	11	11	11	11	11	11	
C _{pdB}	A port input, B port output		38.1	29	29	29	29	30	30	
	B port input, A port output		25.4	19	18	18	18	21	21	
C _{pdA}	A port input, B port output	C _L = 0, f = 10 MHz, t _r = t _f = 1 ns, OE = GND (outputs disabled)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
	B port input, A port output		0.01	0.01	0.01	0.01	0.01	0.01	0.01	
C _{pdB}	A port input, B port output		0.01	0.01	0.01	0.01	0.01	0.01	0.02	
	B port input, A port output		0.01	0.01	0.01	0.01	0.01	0.02	0.03	

6.7 V_{CCA} = 1.2 V Timing Requirements

T_A = 25°C, V_{CCA} = 1.2 V

			V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	V _{CCB} = 5 V	UNIT
			TYP	TYP	TYP	TYP	
Data rate			20	20	20	20	Mbps
t _w	Pulse duration	Data inputs	50	50	50	50	ns

6.8 V_{CCA} = 1.5 V ± 0.1 V Timing Requirements

over recommended operating free-air temperature range, V_{CCA} = 1.5 V ± 0.1 V (unless otherwise noted)

			V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate			40		40		40		40		Mbps
t _w	Pulse duration	Data inputs	25		25		25		25		ns

6.9 V_{CCA} = 1.8 V ± 0.15 V Timing Requirements

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (unless otherwise noted)

			V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate			60		60		60		60		Mbps

V_{CCA} = 1.8 V ± 0.15 V Timing Requirements (continued)

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (unless otherwise noted)

			V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration	Data inputs	17		17		17		17		ns

6.10 V_{CCA} = 2.5 V ± 0.2 V Timing Requirements

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (unless otherwise noted)

			V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate			100		100		100	Mbps
t _w	Pulse duration	Data inputs	10		10		10		ns

6.11 V_{CCA} = 3.3 V ± 0.3 V Timing Requirements

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (unless otherwise noted)

			V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	
	Data rate			100		100	Mbps
t _w	Pulse duration	Data inputs	10		10		ns

6.12 V_{CCA} = 1.2 V Switching Characteristics

T_A = 25°C, V_{CCA} = 1.2 V

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	V _{CCB} = 5 V	UNIT
			TYP	TYP	TYP	TYP	
t _{pd}	A	B	6.9	5.7	5.3	5.5	ns
	B	A	7.4	6.4	6	5.8	
t _{en}	OE	A	1	1	1	1	μs
		B	1	1	1	1	
t _{dis}	OE	A	18	15	14	14	ns
		B	20	17	16	16	
t _{rA}	A port rise time		4.2	4.2	4.2	4.2	ns
t _{fA}	A port fall times		4.2	4.2	4.2	4.2	ns
t _{rB}	B port rise times		2.1	1.5	1.2	1.1	ns
t _{fB}	B port fall times		2.1	1.5	1.2	1.1	ns
t _{sk(o)}	Channel-to-channel		0.5	0.5	0.5	1.4	ns
Max data rate			20	20	20	20	Mbps

6.13 $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	B	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	ns
	B	A	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	
t _{en}	OE	A	1		1		1		1		µs
		B	1		1		1		1		
t _{dis}	OE	A	5.9	31	5.7	25.9	5.6	23	5.7	22.4	ns
		B	5.4	30.3	4.9	22.8	4.8	20	4.9	19.5	
t _{rA}	A port rise times		1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
t _{fA}	A port fall times		1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
t _{rB}	B port rise times		0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t _{fB}	B port fall times		0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t _{sk(o)}	Channel-to-channel		0.5		0.5		0.5		0.5		ns
Max data rate			40		40		40		40		Mbps

6.14 $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$ Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd}	A	B	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	ns
	B	A	1.5	12	1.3	8.4	1	7.6	0.9	7.1	
t_{en}	OE	A	1		1		1		1		μs
		B	1		1		1		1		
t_{dis}	OE	A	5.9	31	5.1	21.3	5	19.3	5	17.4	ns
		B	5.4	30.3	4.4	20.8	4.2	17.9	4.3	16.3	
t_{rA}	A port rise times		1	4.2	1.1	4.1	1.1	4.1	1.1	4.1	ns
t_{fA}	A port fall times		1	4.2	1.1	4.1	1.1	4.1	1.1	4.1	ns
t_{rB}	B port rise times		0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t_{fB}	B port fall times		0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
$t_{sk(o)}$	Channel-to-channel		0.5		0.5		0.5		0.5		ns
Max data rate			60		60		60		60		Mbps

6.15 $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd}	A	B	1.1	6.3	1	5.2	0.9	4.7	ns
	B	A	1.2	6.6	1.1	5.1	0.9	4.4	
t_{en}	OE	A	1		1		1		μs
		B	1		1		1		
t_{dis}	OE	A	5.1	21.3	4.6	15.2	4.6	13.2	ns
		B	4.4	20.8	3.8	16	3.9	13.9	
t_{rA}	A port rise times		0.8	3	0.8	3	0.8	3	ns
t_{fA}	A port fall times		0.8	3	0.8	3	0.8	3	ns
t_{rB}	B port rise times		0.7	3	0.5	2.8	0.4	2.7	ns
t_{fB}	B port fall times		0.7	3	0.5	2.8	0.4	2.7	ns
$t_{sk(o)}$	Channel-to-channel		0.5		0.5		0.5		ns
Max data rate			100		100		100		Mbps

6.16 $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	
t _{pd}	A	B	0.9	4.7	0.8	4	ns
	B	A	1	4.9	0.9	4.5	
t _{en}	OE	A	1		1		μs
		B	1		1		
t _{dis}	OE	A	4.6	15.2	4.3	12.1	ns
		B	3.8	16	3.4	13.2	
t _{rA}	A port rise times		0.7	2.5	0.7	2.5	ns
t _{fA}	A port fall times		0.7	2.5	0.7	2.5	ns
t _{rB}	B port rise times		0.5	2.3	0.4	2.7	ns
t _{fB}	B port fall times		0.5	2.3	0.4	2.7	ns
t _{sk(o)}	Channel-to-channel		0.5		0.5		ns
Max data rate			100		100		Mbps

6.17 Typical Characteristics

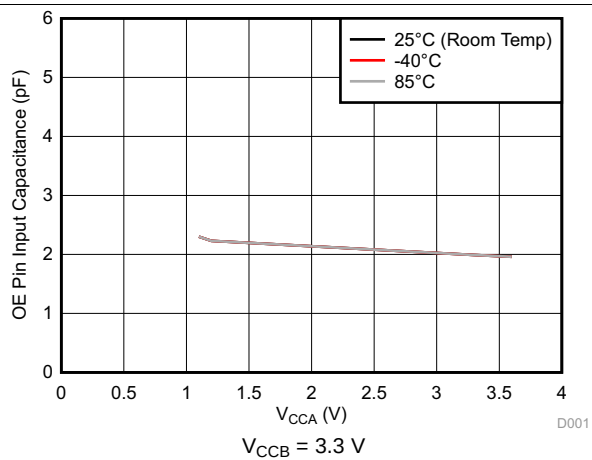


Figure 1. Input Capacitance for OE pin (C_i) vs Power Supply (V_{CCA})

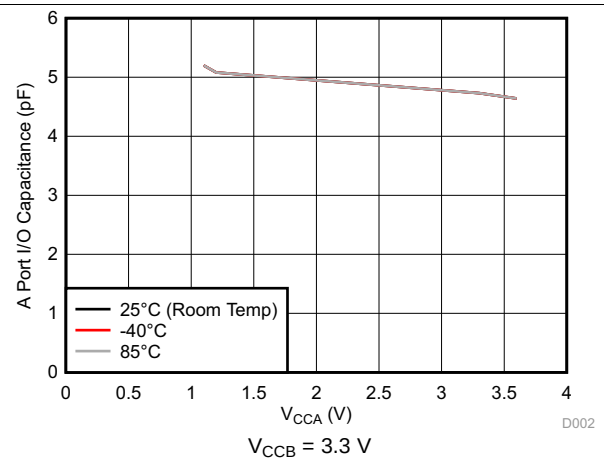


Figure 2. Capacitance for A Port I/O Pins (C_{iO}) vs Power Supply (V_{CCA})

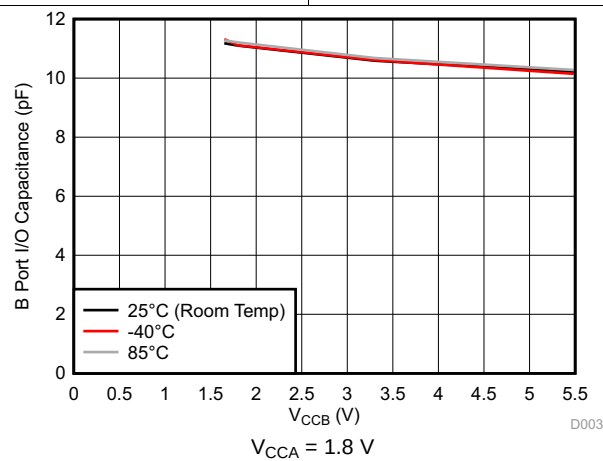
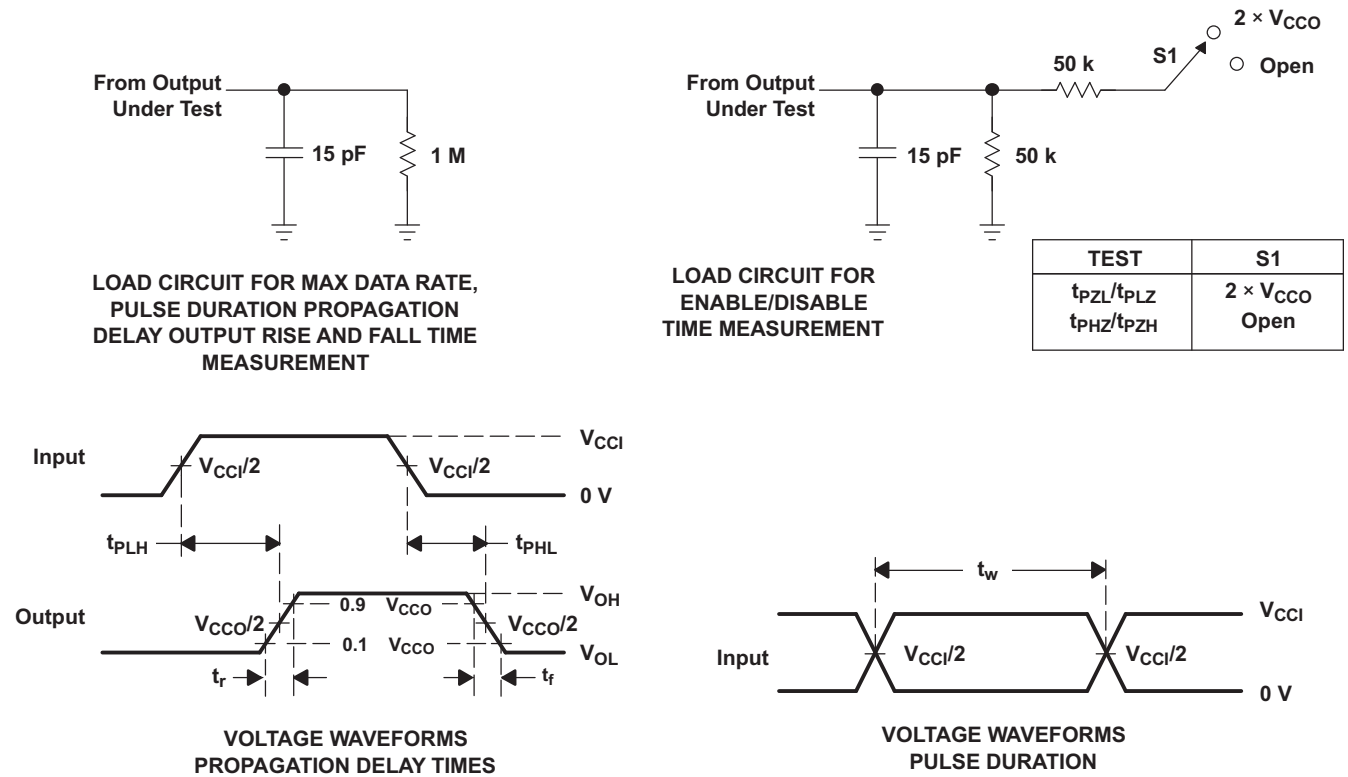


Figure 3. Capacitance for B Port I/O Pins (C_{iO}) vs Power Supply (V_{CCB})

7 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR = 10 MHz, $Z_O = 50 \Omega$, $dv/dt \geq 1$ V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. V_{CCI} is the V_{CC} associated with the input port.
- F. V_{CCO} is the V_{CC} associated with the output port.
- G. All parameters and waveforms are not applicable to all devices.

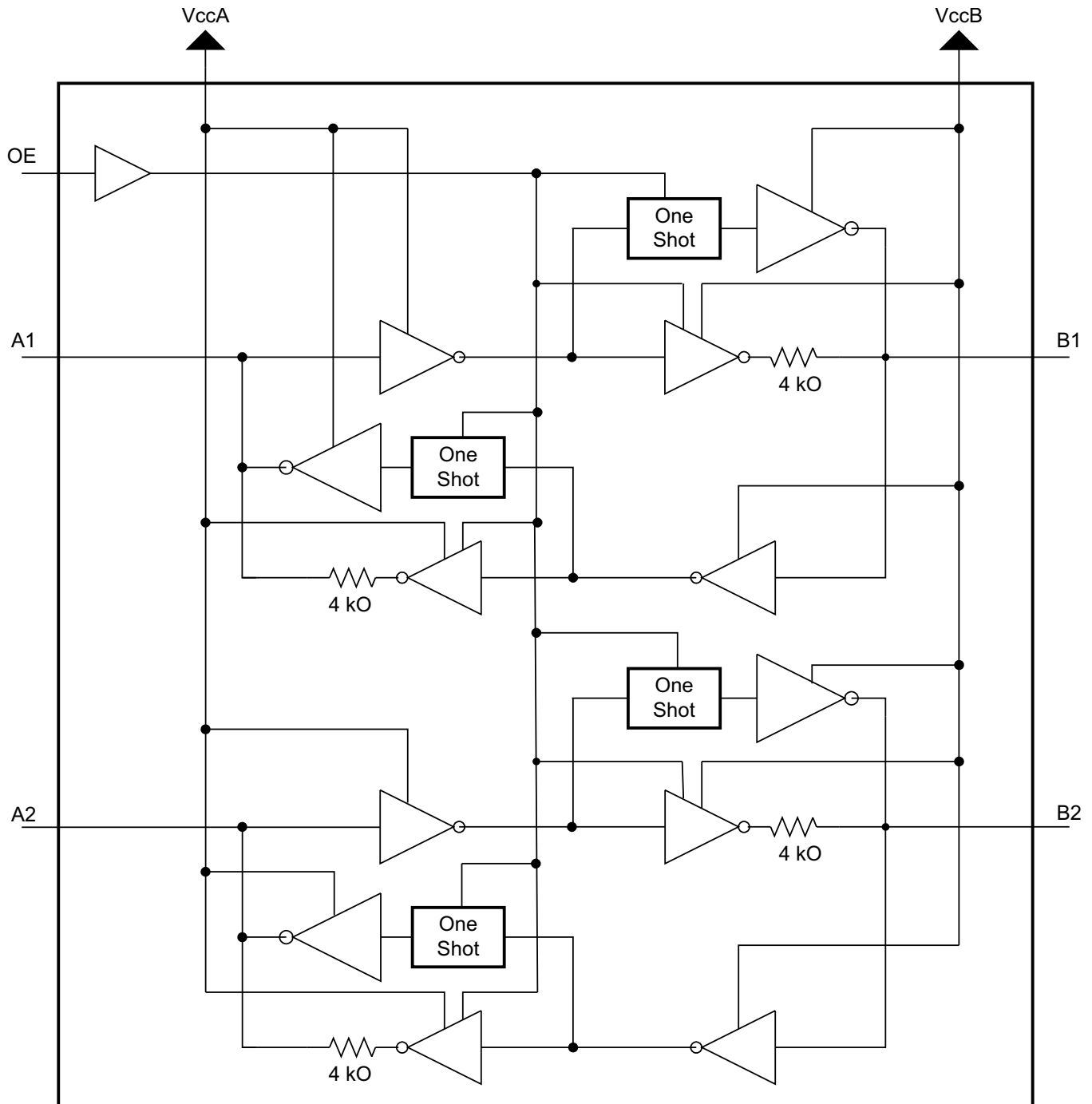
Figure 4. Load Circuits And Voltage Waveforms

8 Detailed Description

8.1 Overview

The TXB0102 device is a 4-bit directionless voltage-level translator specifically designed for translating logic voltage levels. The A port is able to accept I/O voltages ranging from 1.2 V to 3.6 V, while the B port can accept I/O voltages from 1.65V to 5.5V. The device is a buffered architecture with edge rate accelerators (one shots) to improve the overall data rate. This device can only translate push-pull CMOS logic outputs. If for open drain signal translation, please refer to TI TXS010X products.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Architecture

The TXB0102 architecture (see Figure 5) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the TXB0102 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction. The output one shots detect rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70 Ω at VCCO = 1.2 V to 1.8 V, 50 Ω at VCCO = 1.8 V to 3.3 V and 40 Ω at VCCO = 3.3 V to 5 V.

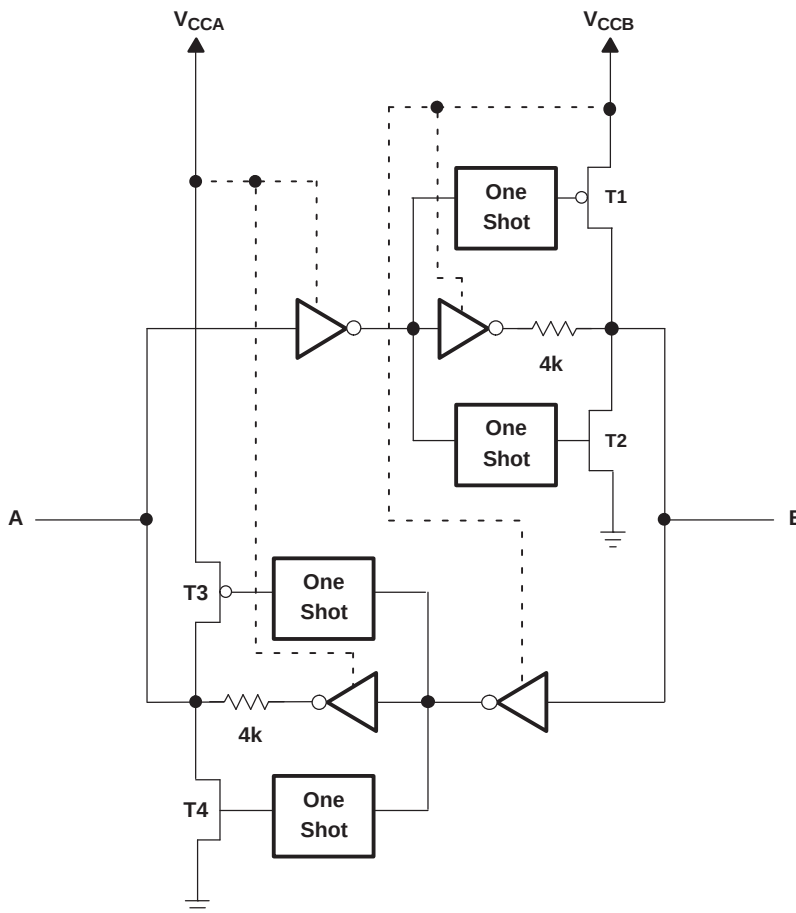


Figure 5. Architecture Of TXB0102 I/O Cell

8.3.2 Input Driver Requirements

Figure 6 shows the typical I_{IN} vs V_{IN} characteristics of the TXB0102. For proper operation, the device driving the data I/Os of the TXB0102 must have drive strength of at least ± 2 mA.

Feature Description (continued)

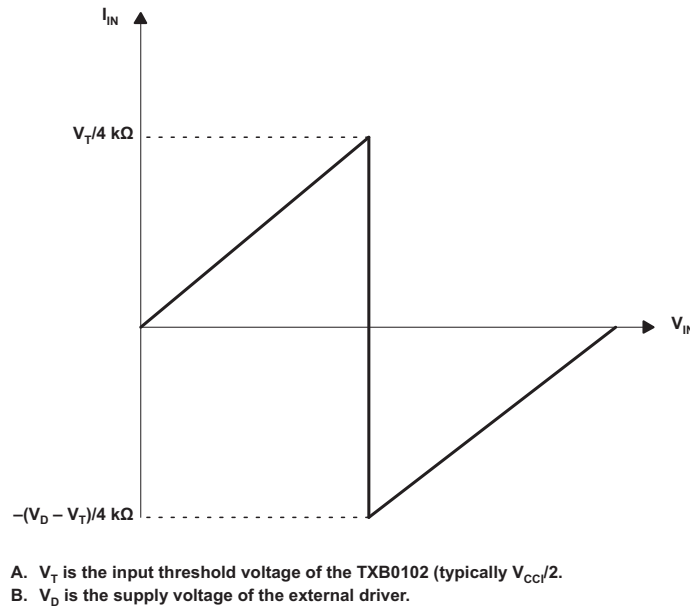


Figure 6. Typical I_{IN} vs V_{IN} Curve

8.3.3 Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 10 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to best optimize trade-offs between dynamic ICC, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the TXB0102 output sees, so it is recommended that this lumped-load capacitance be considered to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

8.3.4 Enable and Disable

The TXB0102 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{dis}) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

8.3.5 Pullup or Pulldown Resistors on I/O Lines

The TXB0102 is designed to drive capacitive loads of up to 70 pF. The output drivers of the TXB0102 have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 kΩ to ensure that they do not contend with the output drivers of the TXB0102.

For the same reason, the TXB0102 should not be used in applications such as I2C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O. For these applications, use a device from the TI TXS01xx series of level translators.

8.4 Device Functional Modes

The TXB0102 device has two functional modes, enabled and disabled. To disable the device set the OE input low, which places all I/Os in a high impedance state. Setting the OE input high will enable the device.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TXB0102 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. It can only translate push-pull CMOS logic outputs. If for open drain signal translation, please refer to TI TXS010X products. Any external pulldown or pullup resistors are recommended larger than 50 kΩ.

9.2 Typical Application

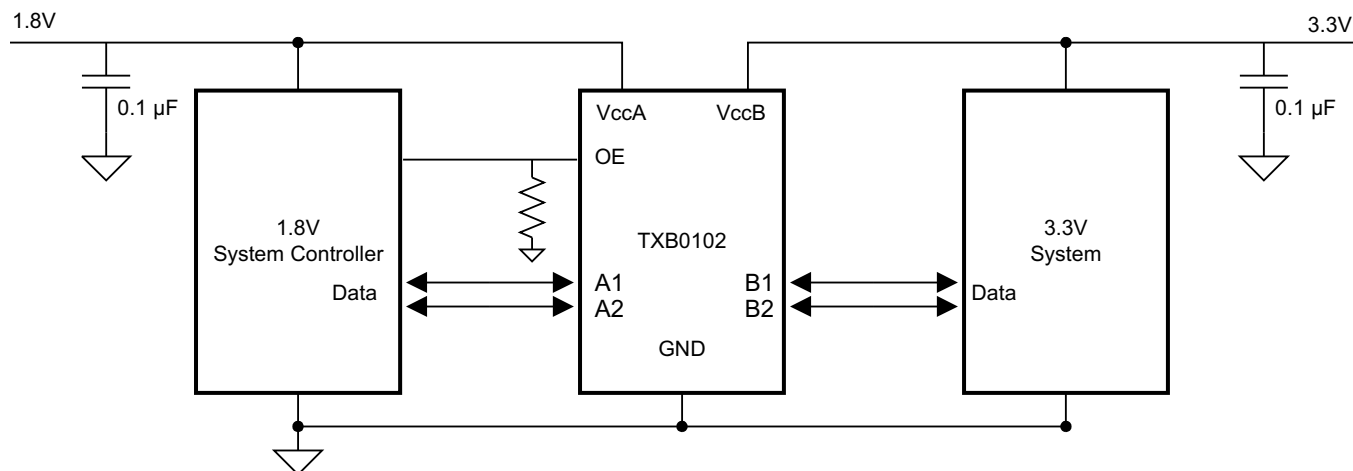


Figure 7. Typical Operating Circuit

9.2.1 Design Requirements

For this design example, use the parameters listed in [Table 1](#). And make sure that $V_{CCA} \leq V_{CCB}$.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.2 V to 3.6 V
Output voltage range	1.65 V to 5.5 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the TXB0102 device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the TXB0102 device is driving to determine the output voltage range.
 - Don't recommend to have the external pullup or pulldown resistors. If mandatory, it is recommended the value should be larger than 50 kΩ.

- An external pulldown or pullup resistor decreases the output V_{OH} and V_{OL} . Use [Equation 1](#) and [Equation 2](#) to draft estimate the V_{OH} and V_{OL} as a result of an external pulldown and pullup resistor.

$$V_{OH} = V_{CCX} \times R_{PD} / (R_{PD} + 4.5 \text{ k}\Omega) \quad (1)$$

$$V_{OL} = V_{CCX} \times 4.5 \text{ k}\Omega / (R_{PU} + 4.5 \text{ k}\Omega)$$

where

- V_{CCX} is the output port supply voltage on either V_{CCA} or V_{CCB}
 - R_{PD} is the value of the external pulldown resistor
 - R_{PU} is the value of the external pullup resistor
 - 4.5 k Ω is the counting the variation of the serial resistor 4 k Ω in the I/O line.
- (2)

9.2.3 Application Curve

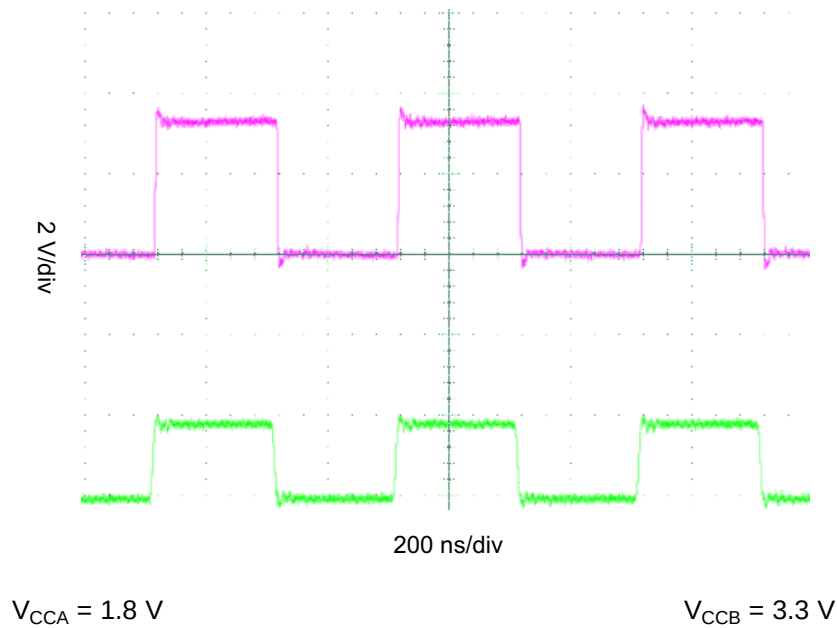


Figure 8. Level-Translation of a 2.5-MHz Signal

10 Power Supply Recommendations

During operation, ensure that $V_{CCA} \leq V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \geq V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The TXB0102 has circuitry that disables all output ports when either V_{CC} is switched off ($V_{CCA/B} = 0$ V). The output-enable (OE) input circuit is designed so that it is supplied by V_{CCA} and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pulldown resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pulldown resistor to ground is determined by the current-sourcing capability of the driver.

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies. And should be placed as close as possible to the V_{CCA} , V_{CCB} pin and GND pin.
- Short trace lengths should be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one shot duration, approximately 10 ns, ensuring that any reflection encounters low impedance at the source driver.

11.2 Layout Example

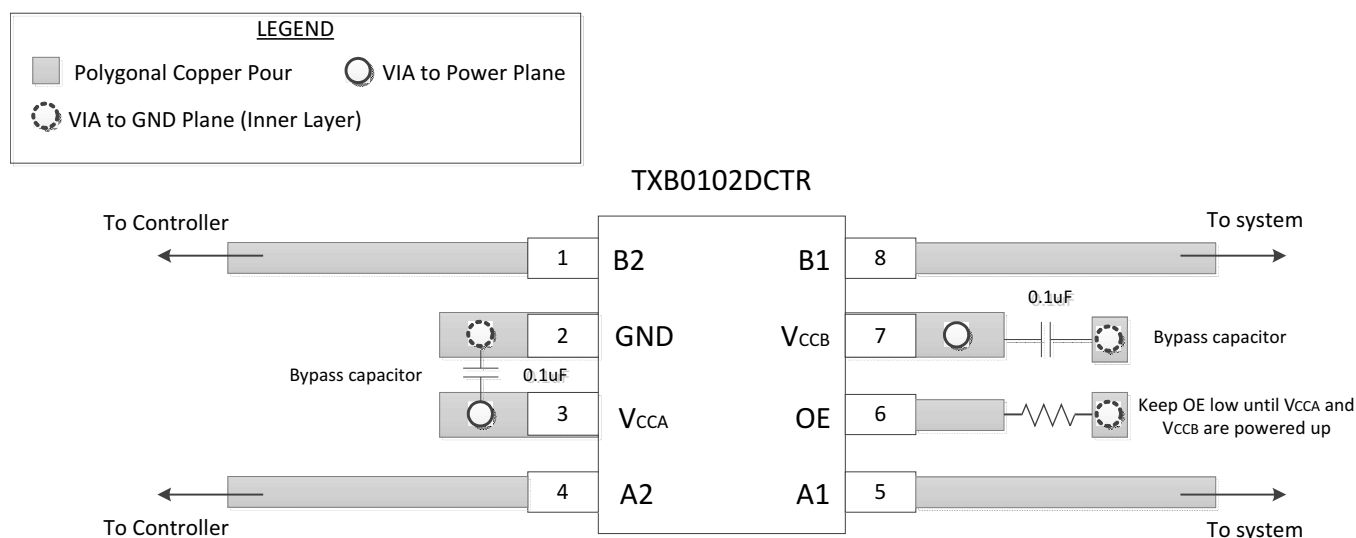


Figure 9. TXB0102 Layout Example

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

A Guide to Voltage Translation With TXB-Type Translators, [SCEA043](#)

12.2 Trademarks

NanoFree is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TXB0102DCUR	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	(FD ~ NFDQ ~ NFDR) NZ	Samples
TXB0102DCURG4	ACTIVE	VSSOP	DCU	8	3000	TBD	Call TI	Call TI	-40 to 85	(FD ~ NFDQ ~ NFDR) NZ	Samples
TXB0102DCUT	ACTIVE	VSSOP	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	(FD ~ NFDQ ~ NFDR) NZ	Samples
TXB0102DCUTG4	ACTIVE	VSSOP	DCU	8	250	TBD	Call TI	Call TI	-40 to 85	(FD ~ NFDQ ~ NFDR) NZ	Samples
TXB0102YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(2E ~ 2E2 ~ 2E7 ~ 2EN)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

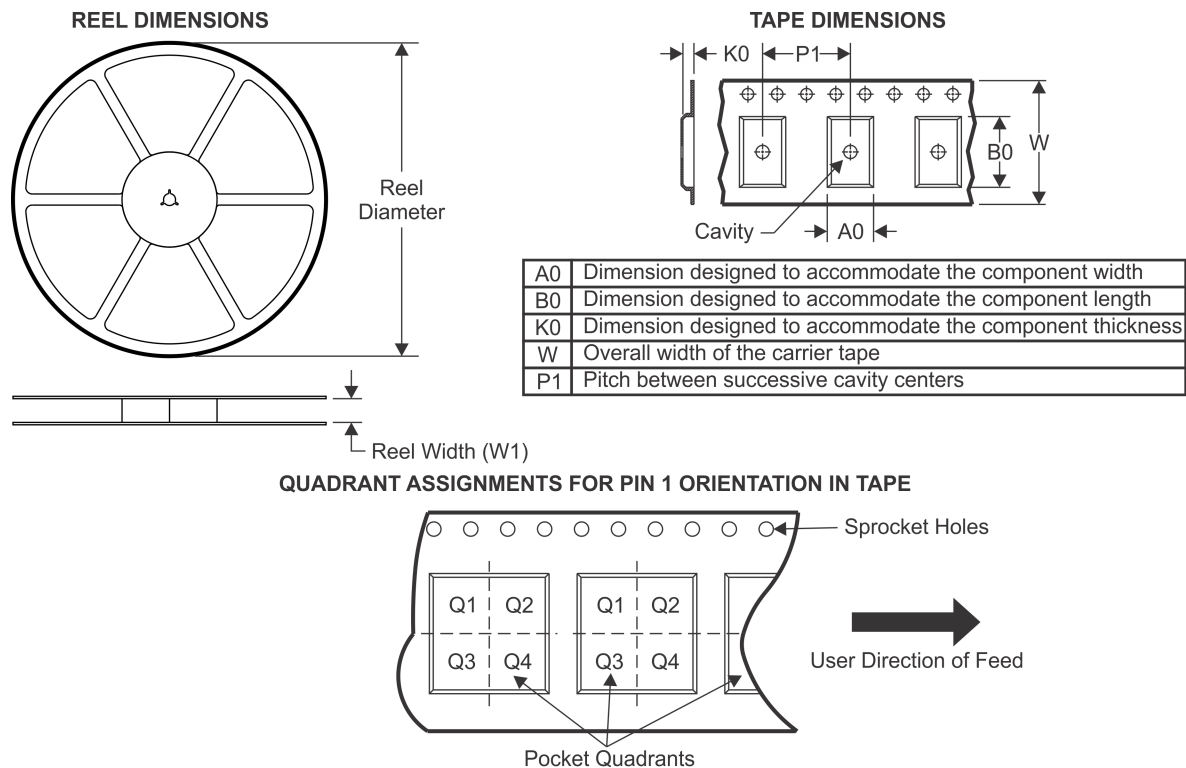
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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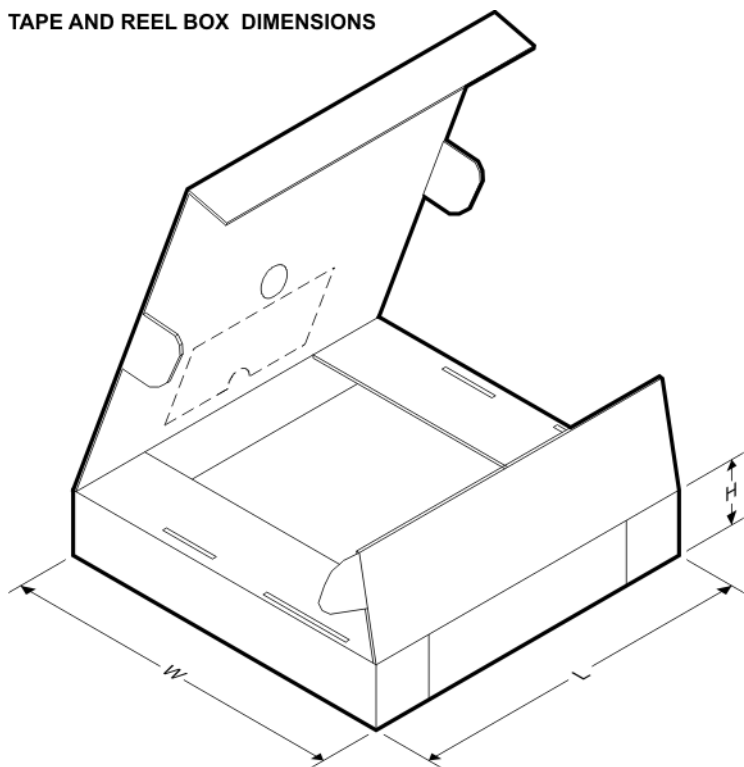
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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXB0102DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
TXB0102YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1
TXB0102YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

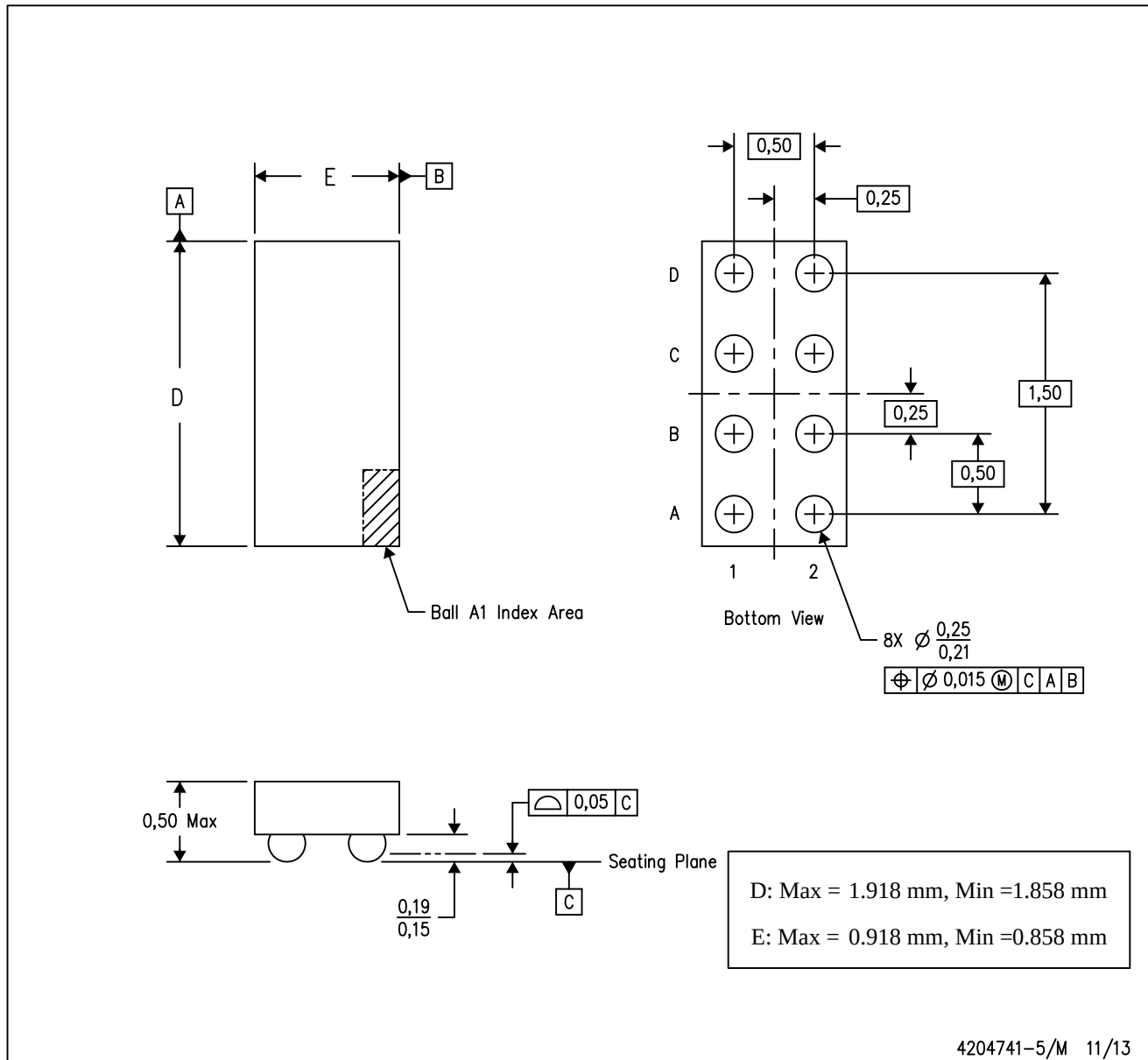


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXB0102DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
TXB0102YZPR	DSBGA	YZP	8	3000	182.0	182.0	20.0
TXB0102YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY

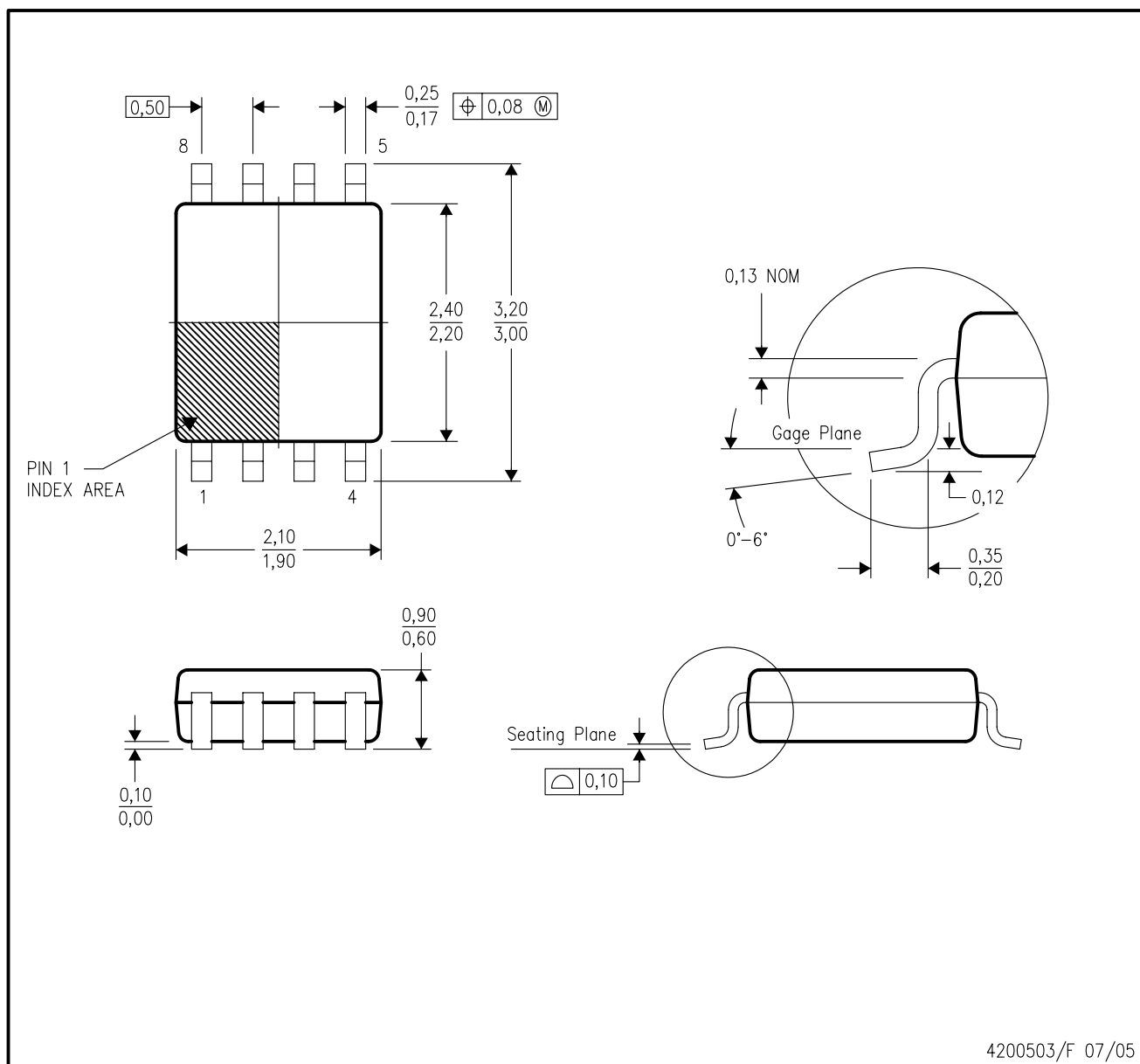


- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)

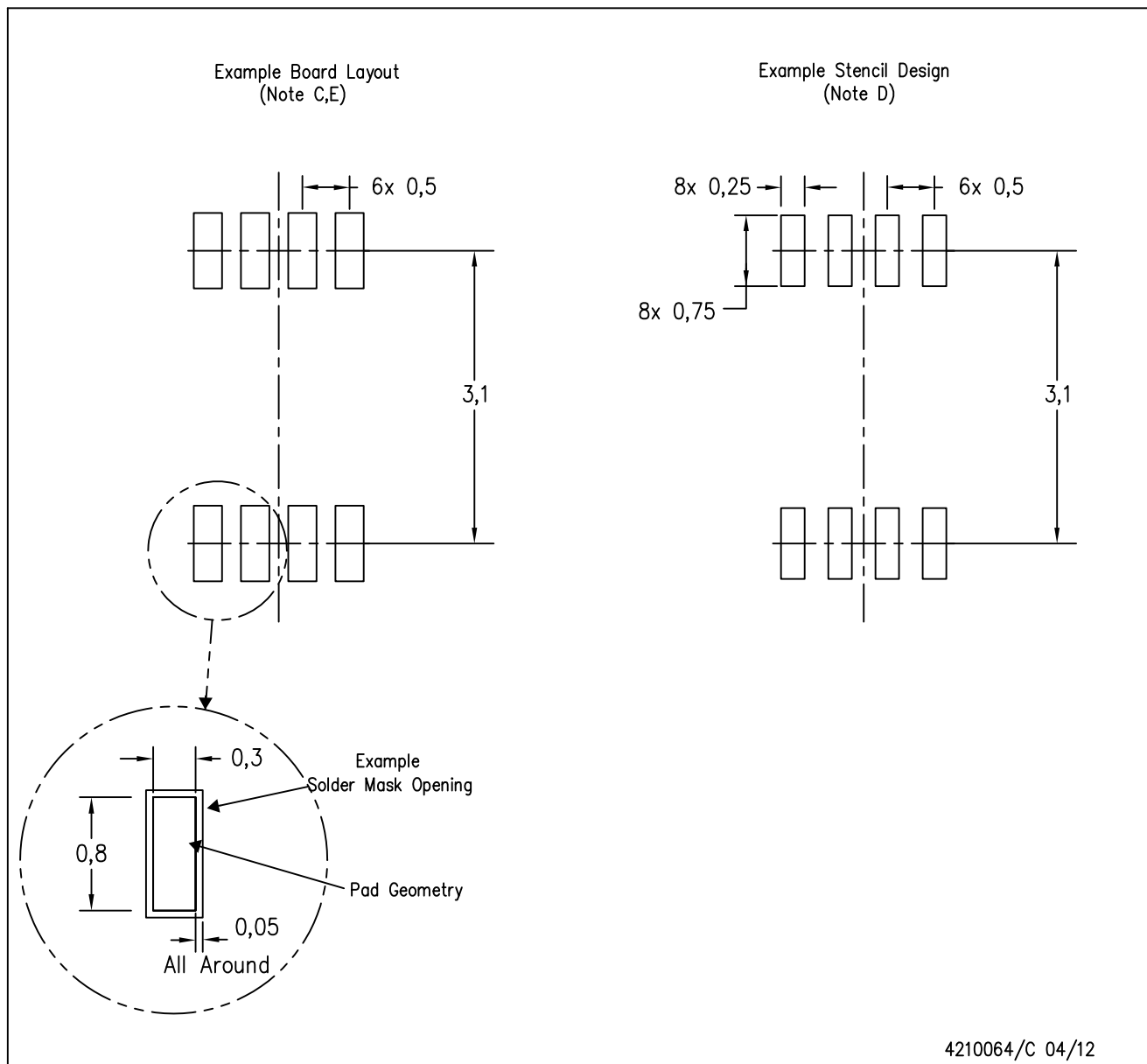


NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- Falls within JEDEC MO-187 variation CA.

DCU (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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